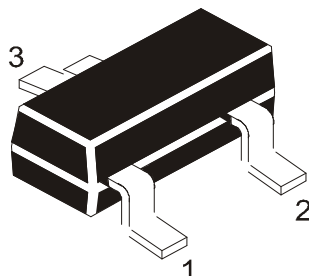


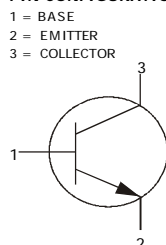
NPN SILICON PLANAR EPITAXIAL TRANSISTORS

CMBT8098
CMBT8099

SOT-23
Formed SMD Package



PIN CONFIGURATION (NPN)



Marking

CMBT8098- KA

CMBT8099- KB

ABSOLUTE MAXIMUM RATING

DESCRIPTION	SYMBOL	CMBT8098	CMBT8099	UNITS
Collector Base Voltage	V_{CBO}	60	80	V
Collector Emitter Voltage	V_{CEO}	60	80	V
Emitter Base Voltage	V_{EBO}	6.0		V
Collector Current Continuous	I_C	500		mA
Power Dissipation $T_a=25^\circ\text{C}$ (Note1)	P_D	225		mW
Derate Above 25°C		1.8		mW/ $^\circ\text{C}$
Power Dissipation $T_a=25^\circ\text{C}$ (Note2)	P_D	300		mW
Derate Above 25°C		2.4		mW/ $^\circ\text{C}$
Operating And Storage Junction Temperature Range	T_j, T_{stg}	- 55 to +150		$^\circ\text{C}$

Thermal Resistance

Junction to Ambient (Note1)	$R_{th(j-a)}$	556	$^\circ\text{C/W}$
Junction to Ambient (Note2)	$R_{th(j-a)}$	417	$^\circ\text{C/W}$

Note (1) FR-5 Board=25.4 x 19.05 x 1.58 mm (1.0 x 0.75 x 0.062 inches.)

Note (2) Alumina Substrate=10.16 x 7.62 x 0.61 mm (0.4 x 0.3 x 0.024 inches.) 99.5% alumina.

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

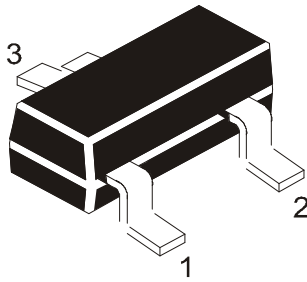
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Base Voltage	V_{CBO}	$I_C=100\mu\text{A}, I_E=0$				
		CMBT8098	60			V
		CMBT8099	80			V
Collector Emitter Voltage	V_{CEO}	$I_C=10\text{mA}, I_B=0$				
		CMBT8098	60			V
		CMBT8099	80			V
Emitter Base Voltage	V_{EBO}	$I_E=10\mu\text{A}, I_C=0$	6.0			V
Collector Cut Off Current	I_{CES}	$V_{CE}=60\text{V}, I_B=0$			0.1	μA
Collector Cut Off Current	I_{CBO}	CMBT8098			0.1	μA
		$V_{CB}=60\text{V}, I_E=0$				
		CMBT8099			0.1	μA
		$V_{CB}=80\text{V}, I_E=0$				
Emitter Cut Off Current	I_{EBO}	$V_{EB}=6\text{V}, I_C=0$			0.1	μA

NPN SILICON PLANAR EPITAXIAL TRANSISTORS

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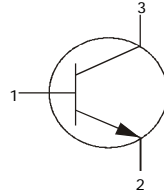
CMBT8098
CMBT8099

SOT-23
Formed SMD Package



PIN CONFIGURATION (NPN)

1 = BASE
2 = EMITTER
3 = COLLECTOR



ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
DC Current Gain	h_{FE}^*	$I_C=1\text{mA}, V_{CE}=5\text{V}$ $I_C=10\text{mA}, V_{CE}=5\text{V}$ $I_C=100\text{mA}, V_{CE}=5\text{V}$	100 100 75		300	
Collector Emitter Saturation Voltage	$V_{CE(sat)}^*$	$I_C=100\text{mA}, I_B=5\text{mA}$ $I_C=100\text{mA}, I_B=10\text{mA}$			0.4 0.3	V V
Base Emitter On Voltage	$V_{BE(on)}^*$	CMBT8098 $I_C=1\text{mA}, V_{CE}=5\text{V}$ CMBT8099 $I_C=10\text{mA}, V_{CE}=5\text{V}$	0.5 0.6		0.7 0.8	V V

Small Signal Characteristics

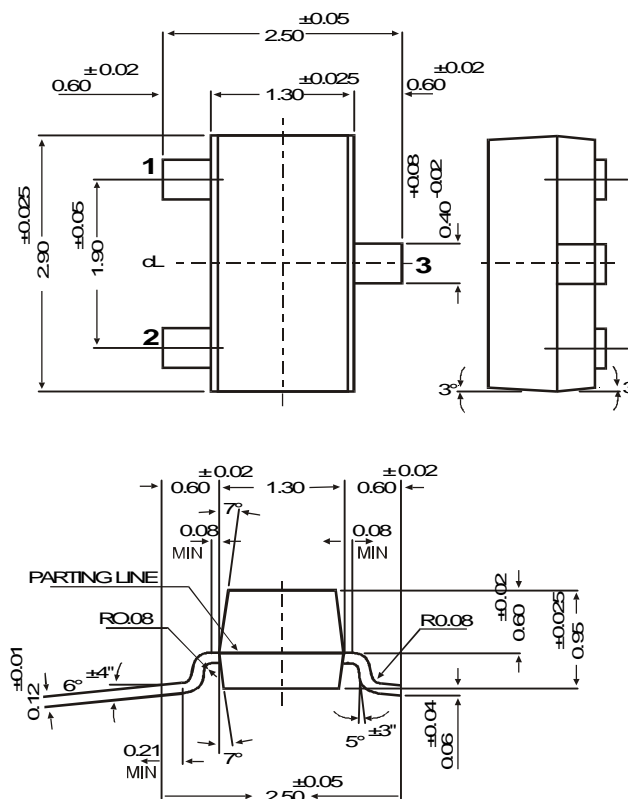
Current Gain Bandwidth Product	f_T	$I_C=10\text{mA}, V_{CE}=5\text{V}, f=100\text{MHz}$	150			MHz
Output Capacitance	C_{obo}	$I_E=0, V_{CB}=5\text{V}, f=1\text{MHz}$			6.0	pF
Input Capacitance	C_{ibo}	$I_C=0, V_{EB}=0.5\text{V}, f=1\text{MHz}$			25	pF

*Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

SOT-23

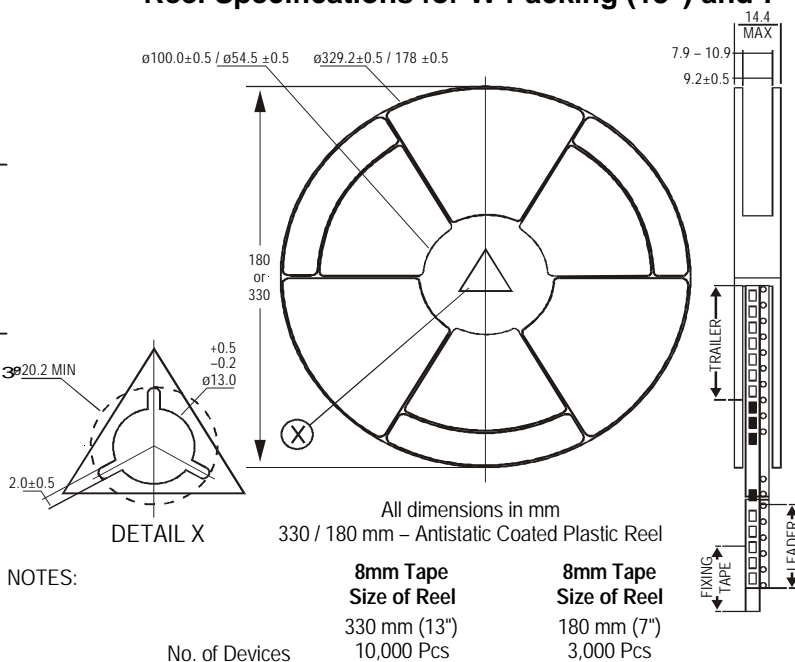
Formed SMD Package

SOT-23 Formed SMD Package



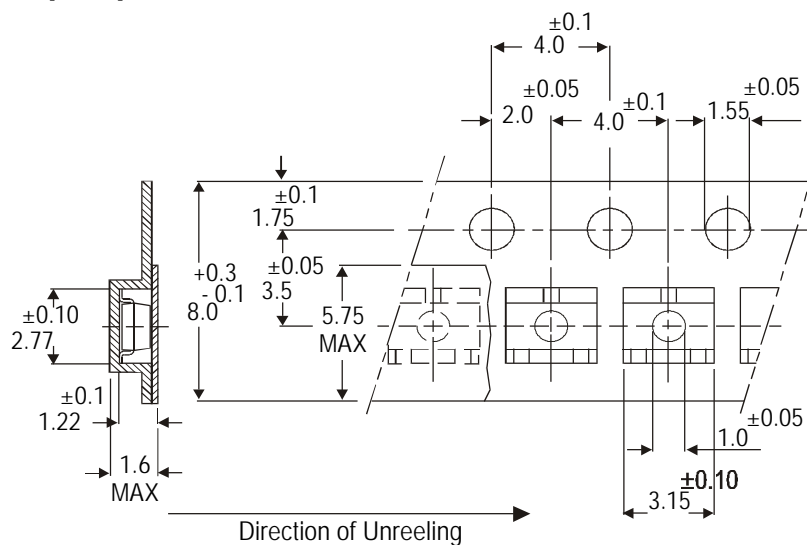
SOT-23 Package Reel Information

Reel Specifications for W Packing (13") and 7"



1. The bandolier of 330 mm reel contains at least 10,000 devices.
2. The bandolier of 180 mm reel contains at least 3,000 devices.
3. No more than 0.5% missing devices / reel. 50 empty compartments for 330 mm reel. 15 empty compartments for 180 mm reel.
4. Three consecutive empty places might be found provided this gap is followed by 6 consecutive devices.
5. The carrier tape (leader) starts with at least 75 empty positions (equivalent to 330 mm). In order to fix the carrier tape a self adhesive tape of 20 to 50 mm is applied. At the end of the bandolier at least 40 empty positions (equivalent to 160 mm) are there.

Tape Specification for SOT-23 Surface Mount Device



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
SOT-23 T&R	3K/feel	136 gm/3K pcs	3" x 7.5" x 7.5"	12 K	17" x 15" x 13.5"	192 K	12 kgs
			9" x 9" x 9"	51 K	19" x 19" x 19"	408 K	28 kgs
	10K/feel	415 gm/10K pcs	13" x 13" x 0.5"	10 K	17" x 15" x 13.5"	300 K	16 kgs

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